Design of Metal MUMPs based LLC Resonant Converter for On-chip Power Supplies

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Abstract— In this paper, a novel Metal MUMPs based tunable LLC converter is proposed for on chip power supplies applications. The design is optimized at 20MHz resonant frequency of LLC tank network and MEMS based tunable capacitor is fabricated on the chip to tune the peak resonance frequency of circuit due to the variation of load. The Design is simulated in FEM based numerical software COMSOL and Intellisuite. From the analysis a magnetizing inductance of 14nH a leakage inductance of 48nH has been achieved from 3.6 mm² rectangular coil transformer. The total capacitance of 1300pF has been achieved from parallel plate capacitor and variation of 3pF has been achieved from tunable capacitor. The passive components on LLC tank network have been fabricated on the same chip.

Keywords—resonant tank network; Intellisuite; magnetizing inductance; Leakage inductance; COMSOL

I. INTRODUCTION

With the advent of resonant power converters many of the problems of pulse width modulation converters (PWM) have been solved. The main problem in high frequency converters is the high switching loss in converters. In resonance converters the switches are softly commutated, therefore the switching loss can be easily reduced and this can also reduce the size of magnetic components by increasing frequency. Traditionally, resonant converter includes series resonant converter (SRC), parallel resonant converter (PRC) and series parallel resonant (SPRC) converters. The problem with series resonant converter is that at light load switching frequency has to increase in order to keep the output voltage regulated. In parallel resonant converter (PRC) circulating energy is much higher even at light load or no load. In series parallel resonant converter (SPRC) the main problem is the wide input range, which leads to high conduction and switching loss at high frequencies.

The LLC resonant converter [1] is a popular topology for its advantages over other resonant converters. It can regulate output voltage over wide line and load variations and with small variation in frequency. It can also achieve zero voltage switching (ZVS) over entire range of operation. It can be used

in wide range of applications such as mobile phones with switched mode power supplies increase battery life. Similarly it can be used in implantable medical devices in human body [2] and can provide power to sensors and actuators in the systems efficiently. Also, it can provide efficient power supply from small solar panel to sensors in wireless sensor network. It can be used as DC-DC converter in power management ICs for micro scale robots for handling the variety of input voltages and supplying power for both actuators and control circuitry.

A lot of research has been done on LLC converters and many designs of LLC have been presented in [3] and [4] and the performance and behavior are completely analyzed. LLC resonant converter is implemented by using half-bridge MOSFETs in zero voltage switching (ZVS) condition and keeping voltage regulation at the output even at no load. So far no research has been done on LLC converter on chip implementation. This is the basic requirement of power supplies on chip. Similarly the load variation also shifts the peak resonance frequency of tank circuit. Thus, the input voltage frequency should vary with the variation of load to achieve regulated output.

Several integrated inductors have been presented for DC-DC converters in [5] and their performances have been compared with a specially designed and fabricated 10MHz inductor. Furthermore, the prototype is tested with a commercially available 8 MHz buck converter.

Many designs of on chip transformers have been presented in [6] for DC-DC converters having different dimensions, shapes, and core materials. The racetrack shape micro-transformer has been presented in [7] with voltage gain of -1 dB between 1-20M Hz frequency range. The turn ratio of transformer is 4:4 with dimension of 2.1mm×11.3 mm. Similarly integrated air core transformer is presented in [8]. The transformer is silicon-embedded and coreless for DC-DC conversion while optimized at 50MHz with the total size of 2 mm². Several power supplies on chip (PwrSoC) and power supplies in package (PwrSiP) have been presented in [9, 10, 11] and it is investigated that PwrSoC and PwrSiP have a higher power density than the conventional power modules.

In this paper, a new integrated LLC converter having tunable capacitor and micro-transformer has been proposed for

power supplies on chip applications. The tunable capacitor is used to tune the resonant frequency of resonant tank with respect to the change in load in order to maintain voltage regulation. The design is optimized using finite element method (FEM) analysis software, Intellisuite and COMSOL. The electromechanical tuning capacitor has been simulated in MEMS specialized Intellisuite software whereas the magnetic component micro-transformer has been simulated using AC/DC module of COMSOL. The prototype is implemented in MEMS standard process, Metal MUMPs from MEMSCAP which is low cost and commercially available.

II. PROPOSED DESIGN

The LLC resonant converter has three main parts as shown in fig.1. The switching part consists of MOSFETs, Q1 and Q2 which is used to produce a unipolar square-wave voltage, V_d . The second part is resonant circuit. The resonant network consists of resonant capacitance, C_r and two inductances Leakage inductance, L_r and Magnetizing inductance, L_m . The third part is rectifier circuit on the secondary side. The four diodes connecting in bridge make a full wave rectifier to convert the AC signal into DC signal which is supplied to the load.

The energy in the resonant circuit circulates in the tank circuit and a part of it is delivered to the load through transformer as shown in fig. 1. In proposed design these passive elements are integrated on the same chip with the extremely reduced size of transformer makes the converter for portable devices and wireless energy transmission for biomedical sensors.

Fig 1. LLC resonant converter.

In the proposed design the resonant tank network is integrated on same die with the ability to tune the resonant frequency of the tank network as shown in fig.2. Thus it can overcome the problem of shifting of resonant frequency due to the variation of load at the output side. The resonant frequency of tank network is governed by two inductances and a capacitor. The resonance frequency is calculated by following equations.

$$f_1 = \frac{1}{2\pi\sqrt{L_{lk}C}} \quad (1)$$

$$f_2 = \frac{1}{2\pi\sqrt{(L_m + L_{lk})C}} \quad (2)$$

It is noted from the design procedure given in [4] that higher peak voltage gain is obtained by reducing L_n value in eq.4. where $L_n = \frac{L_m}{L_{lk}}$, n is transformer turn ratio, f_o is resonance frequency and R_L is load.

$$M_g = \frac{(j\omega L_m) \parallel R_c}{(j\omega L_m) \parallel R_c + j\omega L_r + \frac{1}{j\omega C_r}} \quad (3)$$

$$Q = \frac{L_m(n^2 R_L)}{2\pi f_o L_n} \quad (4)$$

Fig 2. Integrated LLC resonant converter.

The design of LLC converter is optimized by following guide lines mentioned in [3-4] and parameters of resonant tank network are calculated from the eq.(1) and(2). The first resonance frequency which arises from the leakage inductance is about 20MHz and the second resonance frequency which arises due to the sum of leakage and magnetizing inductance is about 14.35MHz. The values of circuit parameters are shown in table 1.

Table1

Tank circuit parameters	Obtained parameter value
Capacitance, C	1300pF
Leakage inductance, L_{lk}	48nH
Magnetizing Inductance, L_m	14.0nH
Turn ratio	1:1

Fig.3 shows the layout of LLC resonant converter. The transformer has 1/1 turn ratio with NiZn ferromagnetic material glued at the top as illustrated in fig.4. A fixed capacitor and a variable capacitor are fabricated on same chip to achieve total capacitance of about 1300pF.. The variation in the capacitance is about 3pF which can bring about 20 kHz change in frequency.

Fig 3. Layout of LLC resonant converter in Blueprint.

Fig 4. NiZn ferromagnetic material glued on top of transformer.

III. FABRICATION PROCESS

The design is optimized in commercially available low cost Metal MUMPs process and simulated in Fab viewer module of Intellisuite. After simulation, 3D model has been built to validate the structure and fabrication accuracy. The step-by-step process is shown in fig.5

In Metal MUMPs process the base wafer is N-type silicon and a $2\mu\text{m}$ silicon dioxide (SiO_2) is grown to provide electrical isolation from substrate. A $0.5\mu\text{m}$ phosphosilicate glass (PSG) layer which acts as sacrificial layer is grown and patterned by photolithography process with the first mask layer as shown in fig.5 (c). The nitride1 layer with $0.35\mu\text{m}$ thickness is deposited and patterned with combination of nitride 2 layer. The purpose of nitride layers is to provide a protective encapsulation for the polysilicon as shown in fig.5(e). Fourth layer which is polysilicon film is $0.7\mu\text{m}$ thick for electrical cross-over routing, shown in fig.5(d). After polysilicon nitride 2 is deposited, this is patterned with the same nitride1 mask layer. The sixth layer is oxide 2, which is $1.1\mu\text{m}$ of PSG which is released at the final release step to free the mechanical layer of Nickel. Anchor metal is the 7th deposition layer which provides anchors for the metal structure. The metal layer is $20\mu\text{m}$ of electroplated patterned nickel layer and $0.5\mu\text{m}$ gold layer is plated on top of nickel to provide electrical contact pads for wire bonding as shown in fig.5 (i). The last layer is 1-3 μm thick gold layer which can be plated on sidewall of metal layer to provide low electrical contact resistance. In the proposed design micro-transformer turns are obtained from the same layer.

Fig 5. Step by Step fabrication process.

Finally, powder NiZn ferromagnetic material is mixed with polymer and glued at the top of transformer to provide a transformer core only at the top.

IV. DESIGN SIMULATION

A. Transformer design simulation

The proposed transformer is simulated using 3D AC/DC module of COMSOL 4.3v. The magnetizing inductance and leakage inductance of transformer has been simulated using and open and short circuiting of transformer secondary coil. Figs.6, and 7 respectively shows the magnetizing and leakage inductance between 1MHz to 20MHz.

Fig. 6. Mutual inductance vs frequency.

The design is optimized at 20MHz and the simulation results shows mutual inductance of 14.6nH and leakage inductance of about 48.0nH are obtained from the 1/1 ratio transformer with a magnetic core on top of gold coils.

Fig. 8 shows the volume plot of magnetic magnetic flux density. It is noted from the figure that magnetic flux density is maximum at the primary coil and covers the secondary side coil which is beside the primary coil. Furthermore, the maximum flux density is at the center of transformer.

Fig.7. Leakage inductance vs frequency .

Fig.8 Volume plot of magnetic flux density at 20MHz

B. Variable Capacitor Simulation

An H-type suspension tunable capacitor is fabricated on the same substrate with micro-transformer and fixed capacitor. The structure of in tunable capacitor is such that to restrict the motion of parallel plate in x-axis and y-axis and allow only in z-axis displacement under the applied DC voltage to both the plate. The gap between the Ni metal and the nitride layer is $1.1\mu\text{m}$ as shown in fig.9. The natural frequency of tunable capacitor is 1.707KHz which is well below input signal(20MHz) to avoid resonance.

The displacement versus voltage plot is shown in fig.10. It is noted that the curve is almost linear upto 10.5V. After 10.5V an abrupt change in displacement is noted due to pull-in voltage which is given by following equation. It is noted that pull in effect starts at 10.4V with remaining gap of $0.72\mu\text{m}$ between two plates.

$$V_p = \sqrt{8kd_0^3/27\epsilon A} \quad (5)$$

Here k is the spring constant of beams, d_0 is the gap between the parallel plate capacitor, ϵ is the permittivity of free space and ' A ' is the area of parallel plate capacitor.

The total stiffness of the tunable capacitor is calculated through the mechanical deformation of spring coil of tunable capacitor as given in equation (6).

$$K = 4(K_1K_2 / K_1 + K_2) \quad (6)$$

Where K_1 and K_2 is the series combination of cantilever beams as shown in fig. 9. The mechanical spring constant of cantilever beam is given by equation. (7) and (8).

$$K_1 = Ew_1t^3 / 4l_1^3 \quad (7)$$

$$K_2 = Ew_2t^3 / 4l_2^3 \quad (8)$$

Fig.9(a) Layout of variable capacitor.(b).A-A' Cross sectional view of variable capacitor.

Fig. 10 Voltage vs displacement in z-axis plot.

Fig.10 shows that as voltage increases the gap between capacitor plates decreases due to which the change in capacitance increases. After 10.5V, there is sudden change in capacitance, that arises due to pull-in effect, which is difficult to calibrate. It is noted from the fig.11 that a total change of about 3pF can be obtain from the proposed design of tunable capacitor.

Fig. 11 Voltage vs change in capacitance plot.

V. CONCLUSIONS

A novel LLC resonant converter based on metal MUMPs with resonance frequency tuning has been proposed. The behavior of tuning capacitor has been through mathematical

modeling and simulation. The micro-transformer is simulated in AC/DC module of COMSOL and MEMS based variable capacitor is simulated in Intellisuite. The design is implemented in commercially available standard process Metal Mumps which is a low cost reliable process. To improve magnetizing inductance and to avoid EMC interference NiZn ferromagnetic material with polymer is glued at the top of transformer coil. It is observed that 14.6nH magnetizing inductance and 48nH leakage inductance have been obtained from 3.6mm² transformer size at frequency of about 20MHz. The total capacitance of about 1300pF has been achieved from the 12.25mm² fixed capacitor. The total variation of about 3pF has been achieved from the tunable capacitor at 10.4V.

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